

#### **Product Summary**

| BV <sub>DSS</sub> | R <sub>DS(ON)</sub>           | Ι <sub>D</sub><br>Ta = +25°C |
|-------------------|-------------------------------|------------------------------|
| 501/              | 1.6Ω @ V <sub>GS</sub> = 10V  | 350mA                        |
| 50V               | 2.5Ω @ V <sub>GS</sub> = 4.5V | 200mA                        |

# **Description and Applications**

This MOSFET has been designed to minimize the on-state resistance (RDs(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor Driving
- Power Management Functions
- Load Switching

#### **Features and Benefits**

- N-Channel MOSFET
- Low On-ResistanceVery Low Gate Threshold Voltage
- Very Low Gate Threshold Voltage
- Low Input CapacitanceFast Switching Speed
- Low Input/ Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

#### **Mechanical Data**

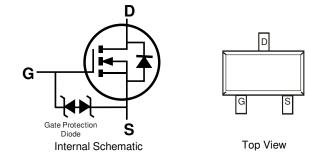
- Case: SOT523
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)





**SOT523** 

Top View



### Ordering Information (Note 4)

|              | Part Number  | Case   | Packaging         |  |  |  |
|--------------|--|--------|-------------------|--|--|--|
|              | DMN53D0LT-7  | SOT523 | 3000/Tape & Reel  |  |  |  |
| DMN53D0LT-13 |  | SOT523 | 10000/Tape & Reel |  |  |  |
| Notes: 1     | lotes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. |        |                   |  |  |  |

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### Marking Information

|               |      |     | T53  | YM   | T53 = Product Type Marking Code<br>YM = Date Code Marking<br>Y or $\overline{Y}$ = Year (ex: H = 2020)<br>M = Month (ex: 9 = September) |      |      |      |      |      |      |      |
|---------------|------|-----|------|------|---|------|------|------|------|------|------|------|
| Date Code Key |      |     |      |      |   | ```  |      |      |      | 0007 | 0000 |      |
| Year          | 2014 | ••• | 2020 | 2021 | 2022  | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 |
| Code          | В    |     | Н    |      | J   | K    | L    | М    | N    | 0    | Р    | R    |
| Month         | Jan  | Feb | Mar  | Apr  | Мау   | Jun  | Jul  | Aug  | Sep  | Oct  | Nov  | Dec  |
| Code          | 1    | 2   | 2    | 4    | 5   | 6    | 7    | 8    | 9    | 0    | N    | D    |



## Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic         | Symbol           | Value | Unit |
|------------------------|------------------|-------|------|
| Drain Source Voltage   | V <sub>DSS</sub> | 50    | V    |
| Gate-Source Voltage    | Vgss             | ±20   | V    |
| Drain Current (Note 5) | ID               | 350   | mA   |

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                   | Symbol               | Value       | Unit |
|--|----------------------|-------------|------|
| Total Power Dissipation (Note 5)                 | PD                   | 300         | mW   |
| Thermal Resistance, Junction to Ambient (Note 5) | R <sub>0JA</sub>     | 420         | °C/W |
| Operating and Storage Temperature Range          | TJ, T <sub>STG</sub> | -55 to +150 | ٥C   |

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

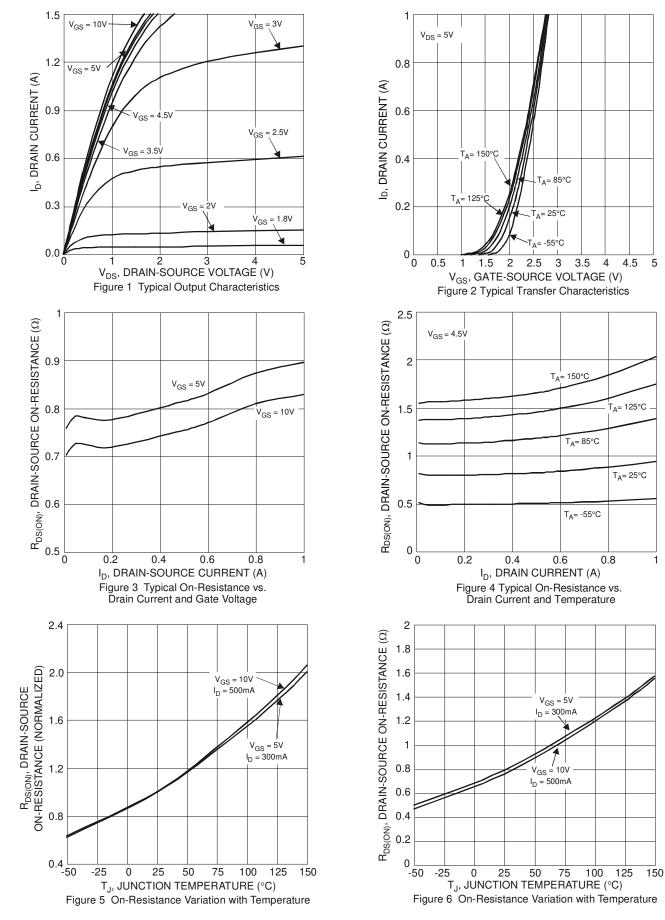
| Characteristic                     | Symbol                      | Min | Тур                  | Max               | Unit | Test Condition  |  |  |
|------------------------------------|-----------------------------|-----|----------------------|-------------------|------|---|--|--|
| OFF CHARACTERISTICS (Note 6)       |                             |     |                      |                   |      | ·   |  |  |
| Drain-Source Breakdown Voltage     | BVDSS                       | 50  | _                    | _                 | V    | $V_{GS} = 0V, I_D = 250 \mu A$                            |  |  |
| Zero Gate Voltage Drain Current    | IDSS                        | _   | _                    | 1.0               | μΑ   | $V_{DS} = 50V, V_{GS} = 0V$                               |  |  |
| Gate-Body Leakage                  | lgss                        | _   | _                    | _                 | μA   | $V_{GS} = \pm 20V, V_{DS} = 0V$                           |  |  |
| ON CHARACTERISTICS (Note 6)        | ON CHARACTERISTICS (Note 6) |     |                      |                   |      |   |  |  |
| Gate Threshold Voltage             | VGS(TH)                     | 0.8 | —                    | 1.5               | V    | $V_{DS} = V_{GS}, I_D = 250 \mu A$                        |  |  |
| Static Drain-Source On-Resistance  | Rds(on)                     |     | 1.08<br>1.09<br>1.45 | 1.6<br>2.5<br>4.5 | Ω    |   |  |  |
| Source-Drain Diode Forward Voltage | Vsd                         | —   | 0.88                 | 1.4               | V    | $V_{GS} = 0V, I_{S} = 500 mA$                             |  |  |
| DYNAMIC CHARACTERISTICS (Note 7)   |                             |     |                      |                   |      |   |  |  |
| Input Capacitance                  | Ciss                        |     | 46                   |                   | pF   | V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V<br>f = 1.0MHz |  |  |
| Output Capacitance                 | Coss                        | _   | 5.3                  |                   | pF   |   |  |  |
| Reverse Transfer Capacitance       | Crss                        | _   | 4.0                  | —                 | pF   |   |  |  |
| Total Gate Charge                  | Qg                          | _   | 0.6                  |                   | nC   |   |  |  |
| Gate-Source Charge                 | Qgs                         | _   | 0.2                  |                   | nC   | VGS = 4.5V, VDS = 10V,<br>ID = 250mA                      |  |  |
| Gate-Drain Charge                  | Q <sub>gd</sub>             | _   | 0.1                  | —                 | nC   |   |  |  |
| Turn-On Delay Time                 | tD(ON)                      |     | 2.7                  | _                 | ns   |   |  |  |
| Turn-On Rise Time                  | tr                          | _   | 2.5                  |                   | ns   | $V_{DD} = 30V, V_{GS} = 10V,$                             |  |  |
| Turn-Off Delay Time                | tD(OFF)                     | _   | 19                   |                   | ns   | $R_{G} = 25\Omega, I_{D} = 200 \text{mA}$                 |  |  |
| Turn-Off Fall Time                 | tF                          |     | 11                   | _                 | ns   | ]   |  |  |

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect. Notes:

7. Guaranteed by design. Not subject to product testing.

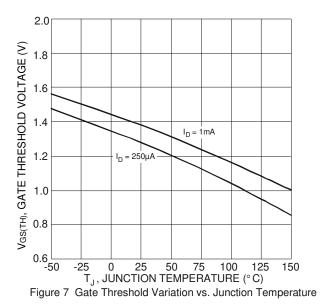


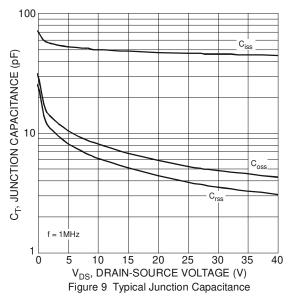
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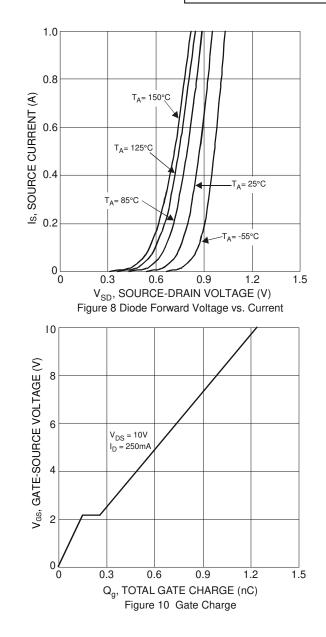




# DMN53D0LT



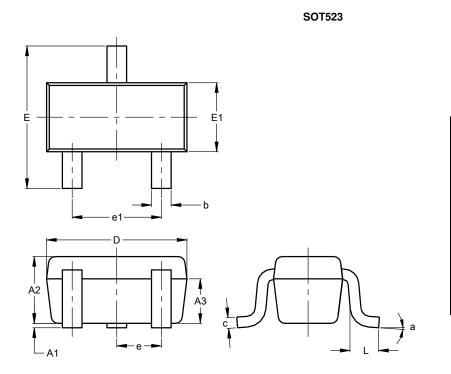






# **Package Outline Dimensions**

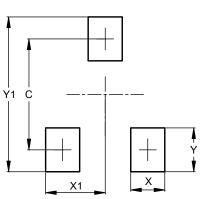
Please see http://www.diodes.com/package-outlines.html for the latest version.



| SOT523               |      |         |      |  |  |  |
|----------------------|------|---------|------|--|--|--|
| Dim                  | Min  | Max     | Тур  |  |  |  |
| A1                   | 0.00 | 0.10    | 0.05 |  |  |  |
| A2                   | 0.60 | 0.80    | 0.75 |  |  |  |
| A3                   | 0.45 | 0.65    | 0.50 |  |  |  |
| b                    | 0.15 | 0.30    | 0.22 |  |  |  |
| С                    | 0.10 | 0.20    | 0.12 |  |  |  |
| D                    | 1.50 | 1.70    | 1.60 |  |  |  |
| Е                    | 1.45 | 1.75    | 1.60 |  |  |  |
| E1                   | 0.75 | 0.85    | 0.80 |  |  |  |
| e                    |      | 0.50 BS | С    |  |  |  |
| e1                   | 0.90 | 1.10    | 1.00 |  |  |  |
| 1                    | 0.20 | 0.40    | 0.33 |  |  |  |
| а                    | 0°   |         | 8°   |  |  |  |
| All Dimensions in mm |      |         |      |  |  |  |

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



| Dimensions | Value<br>(in mm) |
|------------|------------------|
| С          | 1.29             |
| Х          | 0.40             |
| X1         | 0.70             |
| Y          | 0.51             |
| Y1         | 1.80             |

SOT523



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